









SNIS168E - MARCH 2013-REVISED OCTOBER 2017

LMT85

LMT85 1.8-V, SC70/TO-92/TO-92S, **Analog Temperature Sensors**

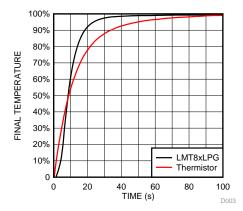
Features

- LMT85LPG (TO-92S package) has a Fast Thermal Time Constant, 10-s Typical (1.2 m/s Airflow)
- Very Accurate: ±0.4°C Typical
- Low 1.8-V Operation
- Average Sensor Gain of -8.2 mV/°C
- Low 5.4-µA Quiescent Current
- Wide Temperature Range: -50°C to 150°C
- Output is Short-Circuit Protected
- Push-Pull Output With ±50-µA Drive Capability
- Footprint Compatible With the Industry-Standard LM20/19 and LM35 Temperature Sensors
- Cost-Effective Alternative to Thermistors

Applications

- Automotive
- Infotainment and Cluster
- Powertrain Systems
- Smoke and Heat Detectors
- **Drones**
- **Appliances**

Thermal Time Constant



^{*} Fast thermal response NTC

3 Description

The LMT85 is a precision CMOS temperature sensor with ±0.4°C typical accuracy (±2.7°C maximum) and a linear analog output voltage that is inversely proportional to temperature. The 1.8-V supply voltage operation, 5.4-μA quiescent current, and 0.7-ms time enable effective power-cycling power-on architectures to minimize power consumption for battery-powered applications such as drones and sensor nodes. The LMT85LPG through-hole TO-92S package fast thermal time constant supports offboard time-temperature sensitive applications such as smoke and heat detectors. The accuracy over the wide operating range and other features make the LMT85 an excellent alternative to thermistors.

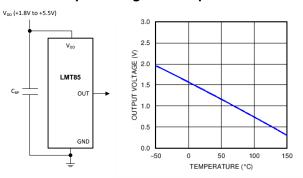
For devices with different average sensor gains and comparable accuracy, refer Comparable to Alternative Devices for alternative devices in the LMT8x family.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LMT85	SOT (5)	2.00 mm × 1.25 mm
	TO-92 (3)	4.30 mm × 3.50 mm
	TO-92S (3)	4.00 mm × 3.15 mm

(1) For all available packages, see the orderable addendum addendum at the end of the data sheet.

Output Voltage vs Temperature



Copyright © 2016, Texas Instruments Incorporated



Table of Contents

Features 1		8.3 Feature Description	
Applications 1		8.4 Device Functional Modes	11
	9	Application and Implementation	13
•		9.1 Application Information	13
•		9.2 Typical Applications	13
	10	Power Supply Recommendations	14
	11		
•			
_		The state of the s	
	12	· ·	
. •			
		•	
**		-	
Detailed Description9	40	•	10
8.1 Overview 9	13		10
8.2 Functional Block Diagram 9		information	10
	numb		Pag
oved the automotive device to a standalone data sheet (SNIS	S200)		<i>*</i>
oved the automotive device to a standalone data sheet (SNIS) nanged TO-92 GND pin number from: 1 to: 3			
			4
	Applications 1 Description 1 Revision History 2 Device Comparison Tables 3 Pin Configuration and Functions 4 Specifications 5 7.1 Absolute Maximum Ratings 5 7.2 ESD Ratings 5 7.3 Recommended Operating Conditions 5 7.4 Thermal Information 5 7.5 Accuracy Characteristics 6 7.6 Electrical Characteristics 6 7.7 Typical Characteristics 7 Detailed Description 9 8.1 Overview 9 8.2 Functional Block Diagram 9	Applications 1 Description 1 Revision History 2 Device Comparison Tables 3 Pin Configuration and Functions 4 To Specifications 5 To Absolute Maximum Ratings 5 To Accuracy Characteristics 6 To Electrical Characteristics 7 Detailed Description 9 Servision History 1 Tevision Histor	Applications 1 8.4 Device Functional Modes

•	Updated data sheet text to the latest documentation and translations standards	. 1
•	Added AEC-Q100 automotive qualification bullets to Features	. 1
•	Added Time Constant graph	. 1
•	Removed disk drivers, games, wireless transceivers, and cell phones from Applications	. 1
•	Added LPG (TO-92S) package	4

Changes	from	Revision	R	(May	2014) to	Revision	C
Citaliges	11 0111	1/6/12/01/	ט	(iviay	2014	, 10	IVEA121011	U

CI	hanges from Revision B (May 2014) to Revision C	Page
•	Deleted all mentions of TO-126 package	1
	Added TO-92 LPM pin configuration graphic	
	Changed Handling Ratings to ESD Ratings and moved Storage Temperature to Absolute Maximum Ratings table	
•	Changed KV to V	5
•	Added TO-92 LP and LPM layout recommendations	15

Changes from Revision A (June 2013) to Revision B

Changed data sheet flow and layout to conform with new TI standards. Added the following sections: Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation Support, Mechanical,

Page



•	Changed from 450°C/W to 275 °C/W. New specification is derived using TI 's latest methodology	5
•	Changed Temperature Accuracy Conditions from 70°C to 20°C and V _{DD} from 1.9V to 1.8V	6
•	Deleted Note: The input current is leakage only and is highest at high temperature. It is typically only 0.001 µA. The	
	1 μA limit is solely based on a testing limitation and does not reflect the actual performance of the part	6

5 Device Comparison Tables

Table 1. Available Device Packages

ORDER NUMBER ⁽¹⁾	PACKAGE	PIN	BODY SIZE (NOM)	MOUNTING TYPE
LMT85DCK	SOT (AKA ⁽²⁾ : SC70, DCK)	5	2.00 mm × 1.25 mm	Surface Mount
LMT85LP	TO-92 (AKA ⁽²⁾ : LP)	3	4.30 mm × 3.50 mm	Through-hole; straight leads
LMT85LPG	TO-92S (AKA ⁽²⁾ : LPG)	3	4.00 mm × 3.15 mm	Through-hole; straight leads
LMT85LPM	TO-92 (AKA ⁽²⁾ : LPM)	3	4.30 mm × 3.50 mm	Through-hole; formed leads
LMT85DCK-Q1	SOT (AKA ⁽²⁾ : SC70, DCK)	5	2.00 mm × 1.25 mm	Surface Mount

⁽¹⁾ For all available packages and complete order numbers, see the Package Option addendum at the end of the data sheet.

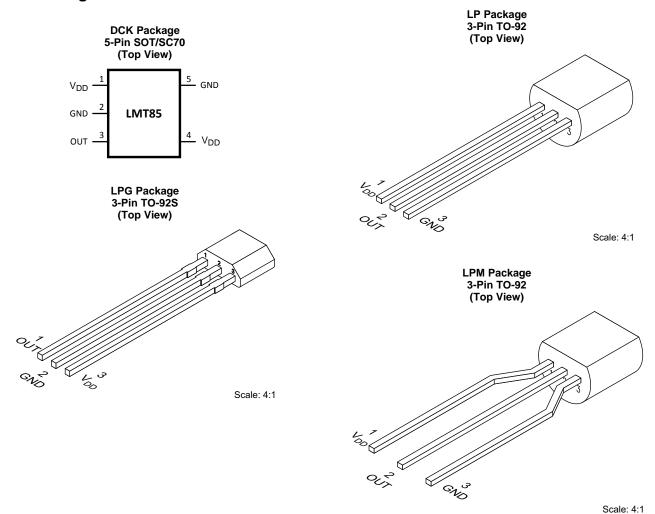
Table 2. Comparable Alternative Devices

DEVICE NAME	AVERAGE OUTPUT SENSOR GAIN	POWER SUPPLY RANGE
LMT84	−5.5 mV/°C	1.5 V to 5.5 V
LMT85	−8.2 mV/°C	1.8 V to 5.5 V
LMT86	−10.9 mV/°C	2.2 V to 5.5 V
LMT87	−13.6 mV/°C	2.7 V to 5.5 V

⁽²⁾ AKA = Also Known As



6 Pin Configuration and Functions



Pin Functions

	i iii i diiddollo						
	PI	IN		TVDE	DESCRIPTION		
NAME	SOT (SC70)	TO-92	TO-92S	TYPE	EQUIVALENT CIRCUIT	FUNCTION	
GND	2 ⁽¹⁾ , 5	3	2	Ground	N/A	Power Supply Ground	
OUT	3	2	1	Analog Output	V _{DD} GND	Outputs a voltage that is inversely proportional to temperature	
V_{DD}	1, 4	1	3	Power	N/A	Positive Supply Voltage	

(1) Direct connection to the back side of the die



7 Specifications

7.1 Absolute Maximum Ratings

See (1)(2)

	MIN	MAX	UNIT
Supply voltage	-0.3	6	٧
Voltage at output pin	-0.3	$(V_{DD} + 0.5)$	V
Output current	-7	7	mA
Input current at any pin (3)	- 5	5	mA
Maximum junction temperature (T _{JMAX})		150	°C
Storage temperature, T _{stg}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability

(2) Soldering process must comply with Reflow Temperature Profile specifications. Refer towww.ti.com/packaging.

7.2 ESD Ratings

			VALUE	UNIT		
LMT85L	LMT85LP in TO-92/TO-92S package					
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)(2)	±2500	V			
	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (3)	±1000	V		
LMT85D	LMT85DCK in SC70 package					
V Electrostatic		Human-body model (HBM), per JESD22-A114 ⁽²⁾	±2500	V		
V _(ESD)	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (3)	±1000	V		

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) The human body model is a 100-pF capacitor discharged through a 1.5-k Ω resistor into each pin.

7.3 Recommended Operating Conditions

<u></u>			
	MIN	MAX	UNIT
Specified temperature	$T_{MIN} \le T_A \le T_{MAX}$		°C
Specified temperature	$-50 \le T_A \le 150$		°C
Supply voltage (V _{DD})	1.8	5.5	V

7.4 Thermal Information⁽¹⁾

	(0)	LMT85/ LMT85-Q1	LMT85LP	LMT85LPG	
	THERMAL METRIC (2)	DCK (SOT/SC70)	LP/LPM (TO-92)	LPG (TO-92S)	UNIT
		5 PINS	3 PINS	3 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance (3)(4)	275	167	130.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	84	90	64.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	56	146	106.2	°C/W
ΨЈТ	Junction-to-top characterization parameter	1.2	35	14.6	°C/W
ΨЈВ	Junction-to-board characterization parameter	55	146	106.2	°C/W

⁽¹⁾ For information on self-heating and thermal response time, see section Mounting and Thermal Conductivity.

(2) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report.

(4) Changes in output due to self-heating can be computed by multiplying the internal dissipation by the thermal resistance.

³⁾ When the input voltage (V_1) at any pin exceeds power supplies $(V_1 < GND \text{ or } V_1 > V)$, the current at that pin should be limited to 5 mA.

⁽³⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

⁽³⁾ The junction to ambient thermal resistance (R_{0,JA}) under natural convection is obtained in a simulation on a JEDEC-standard, High-K board as specified in JESD51-7, in an environment described in JESD51-2. Exposed pad packages assume that thermal vias are included in the PCB, per JESD 51-5.



7.5 Accuracy Characteristics

These limits do not include DC load regulation. These stated accuracy limits are with reference to the values in Table 3.

PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
	$T_A = T_J = 20$ °C to 150°C; $V_{DD} = 1.8 \text{ V}$ to 5.5 V	-2.7	±0.4	2.7	°C
	$T_A = T_J = 0$ °C to 150°C; $V_{DD} = 1.9 \text{ V}$ to 5.5 V	-2.7	±0.7	2.7	°C
Temperature accuracy (3)	$T_A = T_J = 0$ °C to 150°C; $V_{DD} = 2.6 \text{ V}$ to 5.5 V		±0.3		°C
	$T_A = T_J = -50$ °C to 0°C; $V_{DD} = 2.3$ V to 5.5 V	-2.7	±0.7	2.7	°C
	$T_A = T_J = -50$ °C to 0°C; $V_{DD} = 2.9$ V to 5.5 V		±0.25		°C

- (1) Limits are specific to TI's AOQL (Average Outgoing Quality Level).
- (2) Typicals are at $T_J = T_A = 25^{\circ}$ C and represent most likely parametric norm.
- (3) Accuracy is defined as the error between the measured and reference output voltages, tabulated in the Transfer Table at the specified conditions of supply gain setting, voltage, and temperature (expressed in °C). Accuracy limits include line regulation within the specified conditions. Accuracy limits do not include load regulation; they assume no DC load.

7.6 Electrical Characteristics

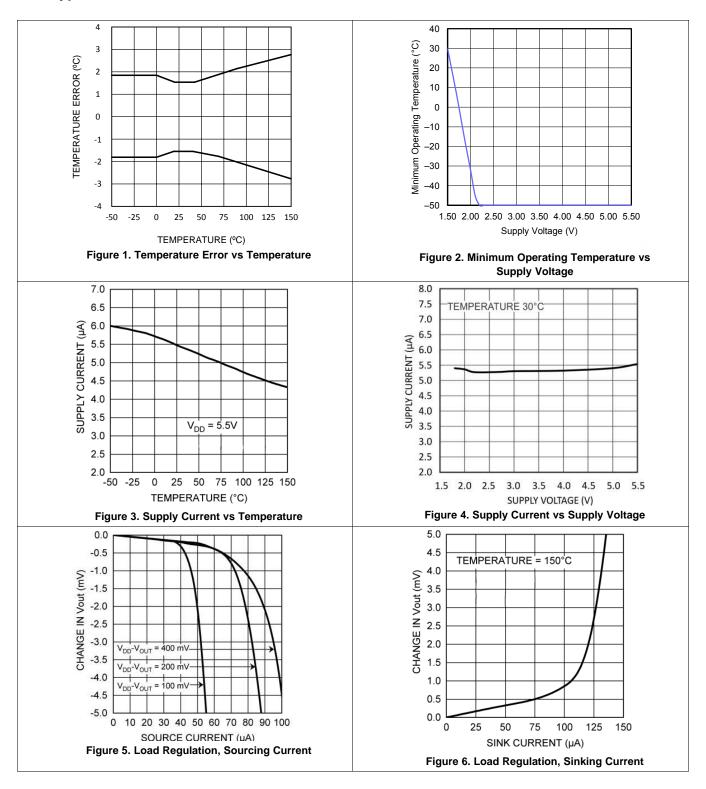
Unless otherwise noted, these specifications apply for V_{DD} = +1.8V to +5.5V. MIN and MAX limits apply for T_A = T_J = T_{MIN} to T_{MAX} , unless otherwise noted; typical values apply for T_A = T_J = 25°C.

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP (2)	MAX ⁽¹⁾	UNIT
	Average sensor gain (output transfer function slope)	-30°C and 90°C used to calculate average sensor gain		-8.2		mV/°C
	Load regulation (3)	Source \leq 50 μ A, (V _{DD} - V _{OUT}) \geq 200 mV	-1	-0.22		mV
	Load regulation (9)	Sink ≤ 50 μA, V _{OUT} ≥ 200 mV		0.26	1	mV
	Line regulation (4)			200		μV/V
Is	Cumply ourrant	$T_A = T_J = 30^{\circ}C \text{ to } 150^{\circ}C, (V_{DD} - V_{OUT}) \ge 100 \text{ mV}$		5.4	8.1	μΑ
	Supply current	$T_A = T_J = -50$ °C to 150°C, $(V_{DD} - V_{OUT}) \ge 100 \text{ mV}$		5.4	9	μΑ
C_L	Output load capacitance			1100		pF
	Power-on time (5)	C _L = 0 pF to 1100 pF		0.7	1.9	ms
	Output drive	$T_A = T_J = 25$ °C	-50		+50	μΑ

- (1) Limits are specific to TI's AOQL (Average Outgoing Quality Level).
- (2) Typicals are at $T_J = T_A = 25$ °C and represent most likely parametric norm.
- (3) Source currents are flowing out of the LMT85. Sink currents are flowing into the LMT85.
- (4) Line regulation (DC) is calculated by subtracting the output voltage at the highest supply voltage from the output voltage at the lowest supply voltage. The typical DC line regulation specification does not include the output voltage shift discussed in Output Voltage Shift.
- (5) Specified by design and characterization.

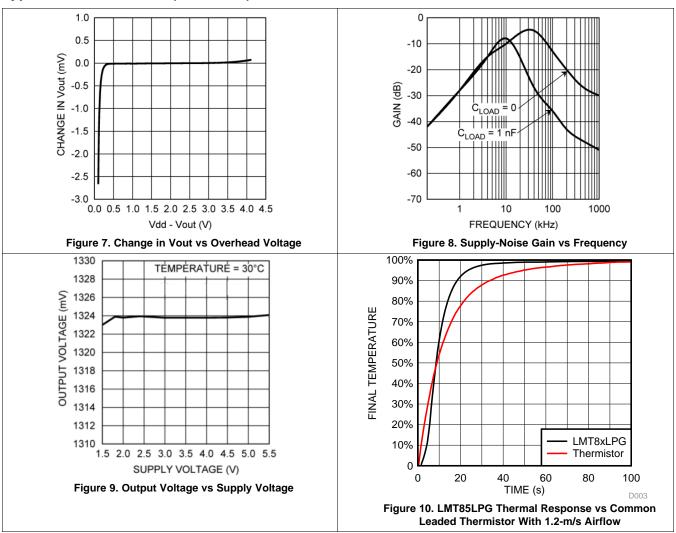


7.7 Typical Characteristics





Typical Characteristics (continued)





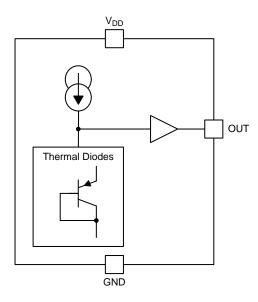
8 Detailed Description

8.1 Overview

The LMT85 is an analog output temperature sensor. The temperature sensing element is comprised of a simple base emitter junction that is forward biased by a current source. The temperature-sensing element is then buffered by an amplifier and provided to the OUT pin. The amplifier has a simple push-pull output stage thus providing a low impedance output source.

8.2 Functional Block Diagram

Full-Range Celsius Temperature Sensor (-50°C to 150°C).



8.3 Feature Description

8.3.1 LMT85 Transfer Function

The output voltage of the LMT85, across the complete operating temperature range, is shown in Table 3. This table is the reference from which the LMT85 accuracy specifications (listed in the *Accuracy Characteristics* section) are determined. This table can be used, for example, in a host processor look-up table. A file containing this data is available for download at the LMT85 product folder under *Tools and Software Models*.

Table 3. LMT85 Transfer Table

TEMP (°C)	V _{OUT} (mV)								
-50	1955	-10	1648	30	1324	70	991	110	651
-49	1949	-9	1639	31	1316	71	983	111	642
-48	1942	-8	1631	32	1308	72	974	112	634
-47	1935	-7	1623	33	1299	73	966	113	625
-46	1928	-6	1615	34	1291	74	957	114	617
-45	1921	-5	1607	35	1283	75	949	115	608
-44	1915	-4	1599	36	1275	76	941	116	599
-43	1908	-3	1591	37	1267	77	932	117	591
-42	1900	-2	1583	38	1258	78	924	118	582
-41	1892	-1	1575	39	1250	79	915	119	573
-40	1885	0	1567	40	1242	80	907	120	565
-39	1877	1	1559	41	1234	81	898	121	556
-38	1869	2	1551	42	1225	82	890	122	547

TEXAS INSTRUMENTS

Feature Description (continued)

Table 3. LMT85 Transfer Table (continued)

TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)						
-37	1861	3	1543	43	1217	83	881	123	539
-36	1853	4	1535	44	1209	84	873	124	530
-35	1845	5	1527	45	1201	85	865	125	521
-34	1838	6	1519	46	1192	86	856	126	513
-33	1830	7	1511	47	1184	87	848	127	504
-32	1822	8	1502	48	1176	88	839	128	495
-31	1814	9	1494	49	1167	89	831	129	487
-30	1806	10	1486	50	1159	90	822	130	478
-29	1798	11	1478	51	1151	91	814	131	469
-28	1790	12	1470	52	1143	92	805	132	460
-27	1783	13	1462	53	1134	93	797	133	452
-26	1775	14	1454	54	1126	94	788	134	443
-25	1767	15	1446	55	1118	95	779	135	434
-24	1759	16	1438	56	1109	96	771	136	425
-23	1751	17	1430	57	1101	97	762	137	416
-22	1743	18	1421	58	1093	98	754	138	408
-21	1735	19	1413	59	1084	99	745	139	399
-20	1727	20	1405	60	1076	100	737	140	390
-19	1719	21	1397	61	1067	101	728	141	381
-18	1711	22	1389	62	1059	102	720	142	372
-17	1703	23	1381	63	1051	103	711	143	363
-16	1695	24	1373	64	1042	104	702	144	354
-15	1687	25	1365	65	1034	105	694	145	346
-14	1679	26	1356	66	1025	106	685	146	337
-13	1671	27	1348	67	1017	107	677	147	328
-12	1663	28	1340	68	1008	108	668	148	319
-11	1656	29	1332	69	1000	109	660	149	310
								150	301

Although the LMT85 is very linear, its response does have a slight umbrella parabolic shape. This shape is very accurately reflected in Table 3. The Transfer Table can be calculated by using the parabolic equation (Equation 1).

$$V_{TEMP}(mV) = 1324.0mV - \left[8.194 \frac{mV}{^{\circ}C} (T - 30^{\circ}C)\right] - \left[0.00262 \frac{mV}{^{\circ}C^{2}} (T - 30^{\circ}C)^{2}\right]$$
(1)

The parabolic equation is an approximation of the transfer table and the accuracy of the equation degrades slightly at the temperature range extremes. Equation 1 can be solved for T resulting in:

$$T = \frac{8.194 - \sqrt{(-8.194)^2 + 4 \times 0.00262 \times (1324 - V_{TEMP} \text{ (mV)})}}{2 \times -0.00262} + 30$$
 (2)

For an even less accurate linear transfer function approximation, a line can easily be calculated over the desired temperature range using values from the Table and a two-point equation (Equation 3):

$$V - V_1 = \left(\frac{V_2 - V_1}{T_2 - T_1}\right) \times (T - T_1)$$

where

- V is in mV.
- T is in °C,
- T₁ and V₁ are the coordinates of the lowest temperature,
- and T₂ and V₂ are the coordinates of the highest temperature.

(3)



For example, if the user wanted to resolve this equation, over a temperature range of 20°C to 50°C, they would proceed as follows:

$$V - 1405 \text{ mV} = \left(\frac{1159 \text{ mV} - 1405 \text{ mV}}{50^{\circ}\text{C} - 20^{\circ}\text{C}}\right) \times (\text{T} - 20^{\circ}\text{C})$$
(4)

V - 1405 mV =
$$(-8.20 \text{ mV} / {}^{\circ}\text{C}) \times (\text{T} - 20 {}^{\circ}\text{C})$$
 (5)

$$V = (-8.20 \text{ mV} / {}^{\circ}\text{C}) \times \text{T} + 1569 \text{ mV}$$
 (6)

Using this method of linear approximation, the transfer function can be approximated for one or more temperature ranges of interest.

8.4 Device Functional Modes

8.4.1 Mounting and Thermal Conductivity

The LMT85 can be applied easily in the same way as other integrated-circuit temperature sensors. It can be glued or cemented to a surface.

To ensure good thermal conductivity, the backside of the LMT85 die is directly attached to the GND pin. The temperatures of the lands and traces to the other leads of the LMT85 will also affect the temperature reading.

Alternatively, the LMT85 can be mounted inside a sealed-end metal tube, and can then be dipped into a bath or screwed into a threaded hole in a tank. As with any IC, the LMT85 and accompanying wiring and circuits must be kept insulated and dry, to avoid leakage and corrosion. This is especially true if the circuit may operate at cold temperatures where condensation can occur. If moisture creates a short circuit from the output to ground or V_{DD} , the output from the LMT85 will not be correct. Printed-circuit coatings are often used to ensure that moisture cannot corrode the leads or circuit traces.

The thermal resistance junction to ambient $(R_{\theta JA} \text{ or } \theta_{JA})$ is the parameter used to calculate the rise of a device junction temperature due to its power dissipation. Use Equation 7 to calculate the rise in the LMT85 die temperature:

$$T_{J} = T_{A} + \theta_{JA} \left[(V_{DD}I_{S}) + (V_{DD} - V_{OUT}) I_{L} \right]$$

where

- T_A is the ambient temperature,
- I_S is the supply current,
- ILis the load current on the output,
- and V_O is the output voltage.

For example, in an application where $T_A = 30^{\circ}\text{C}$, $V_{DD} = 5$ V, $I_S = 5.4$ μA , $V_{OUT} = 1324$ mV, and $I_L = 2$ μA , the junction temperature would be 30.014°C , showing a self-heating error of only 0.014°C . Because the junction temperature of the LMT85 is the actual temperature being measured, take care to minimize the load current that the LMT85 is required to drive. *Thermal Information* shows the thermal resistance of the LMT85.

8.4.2 Output and Noise Considerations

A push-pull output gives the LMT85 the ability to sink and source significant current. This is beneficial when, for example, driving dynamic loads like an input stage on an analog-to-digital converter (ADC). In these applications the source current is required to quickly charge the input capacitor of the ADC. The LMT85 device is ideal for this and other applications which require strong source or sink current.

The LMT85 supply-noise gain (the ratio of the AC signal on V_{OUT} to the AC signal on V_{DD}) was measured during bench tests. The typical attenuation is shown in Figure 8 found in the *Typical Characteristics*. A load capacitor on the output can help to filter noise.

For operation in very noisy environments, some bypass capacitance should be present on the supply within approximately 5 centimeters of the LMT85.



Device Functional Modes (continued)

8.4.3 Capacitive Loads

The LMT85 handles capacitive loading well. In an extremely noisy environment, or when driving a switched sampling input on an ADC, it may be necessary to add some filtering to minimize noise coupling. Without any precautions, the LMT85 can drive a capacitive load less than or equal to 1100 pF as shown in Figure 11. For capacitive loads greater than 1100 pF, a series resistor may be required on the output, as shown in Figure 12.

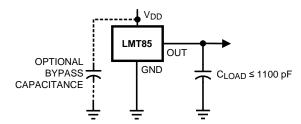


Figure 11. LMT85 No Decoupling Required for Capacitive Loads Less Than 1100 pF

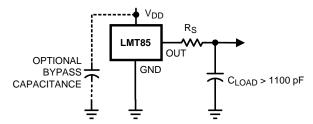


Figure 12. LMT85 with Series Resistor for Capacitive Loading Greater Than 1100 pF

Table 4. Recommended Series Resistor Values

C _{LOAD}	MINIMUM R _S
1.1 nF to 99 nF	3 kΩ
100 nF to 999 nF	1.5 kΩ
1 μF	800 Ω

8.4.4 Output Voltage Shift

The LMT85 is very linear over temperature and supply voltage range. Due to the intrinsic behavior of an NMOS/PMOS rail-to-rail buffer, a slight shift in the output can occur when the supply voltage is ramped over the operating range of the device. The location of the shift is determined by the relative levels of V_{DD} and V_{OUT} . The shift typically occurs when V_{DD} - V_{OUT} = 1 V.

This slight shift (a few millivolts) takes place over a wide change (approximately 200 mV) in V_{DD} or V_{OUT} . Because the shift takes place over a wide temperature change of 5°C to 20°C, V_{OUT} is always monotonic. The accuracy specifications in the *Accuracy Characteristics* table already include this possible shift.



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The LMT85 features make it suitable for many general temperature-sensing applications. It can operate down to 1.8-V supply with 5.4-µA power consumption, making it ideal for battery powered devices. Package options like the through-hole TO-92 package allow the LMT85 to be mounted onboard, off-board, to a heat sink, or on multiple unique locations in the same application.

9.2 Typical Applications

9.2.1 Connection to an ADC

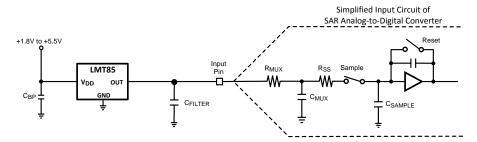


Figure 13. Suggested Connection to a Sampling Analog-to-Digital Converter Input Stage

9.2.1.1 Design Requirements

Most CMOS ADCs found in microcontrollers and ASICs have a sampled data comparator input structure. When the ADC charges the sampling cap, it requires instantaneous charge from the output of the analog source such as the LMT85 temperature sensor and many op amps. This requirement is easily accommodated by the addition of a capacitor (C_{FILTER}).

9.2.1.2 Detailed Design Procedure

The size of C_{FILTER} depends on the size of the sampling capacitor and the sampling frequency. Because not all ADCs have identical input stages, the charge requirements will vary. This general ADC application is shown as an example only.

9.2.1.3 Application Curve

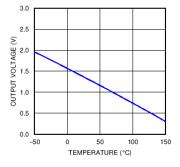


Figure 14. Analog Output Transfer Function



Typical Applications (continued)

9.2.2 Conserving Power Dissipation With Shutdown

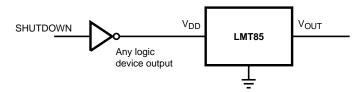


Figure 15. Simple Shutdown Connection of the LMT85

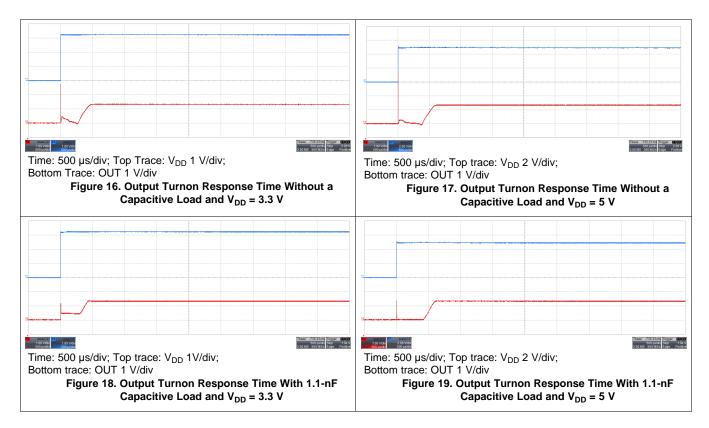
9.2.2.1 Design Requirements

Because the power consumption of the LMT85 is less than $9 \mu A$, it can simply be powered directly from any logic gate output and therefore not require a specific shutdown pin. The device can even be powered directly from a micro controller GPIO. In this way, it can easily be turned off for cases such as battery-powered systems where power savings are critical.

9.2.2.2 Detailed Design Procedure

Simply connect the V_{DD} pin of the LMT85 directly to the logic shutdown signal from a microcontroller.

9.2.2.3 Application Curves



10 Power Supply Recommendations

The low supply current and supply range (1.8 V to 5.5 V) of the LMT85 allow the device to easily be powered from many sources. Power supply bypassing is optional and is mainly dependent on the noise on the power supply used. In noisy systems it may be necessary to add bypass capacitors to lower the noise that is coupled to the output of the LMT85.



11 Layout

11.1 Layout Guidelines

The LMT85 is extremely simple to layout. If a power-supply bypass capacitor is used, it should be connected as shown in the *Layout Example*

11.2 Layout Example

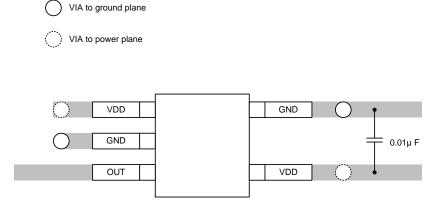


Figure 20. SC70 Package Recommended Layout

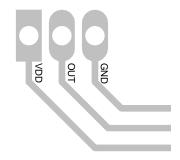


Figure 21. TO-92 LP Package Recommended Layout

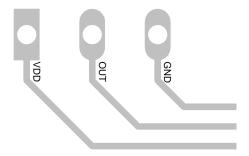


Figure 22. TO-92 LPM Package Recommended Layout



12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



www.ti.com 10-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
						(4)	(5)		
LMT85DCKR	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-50 to 150	BPA
LMT85DCKR.A	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-50 to 150	BPA
LMT85DCKR.B	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-50 to 150	BPA
LMT85DCKT	Obsolete	Production	SC70 (DCK) 5	-	-	Call TI	Call TI	-50 to 150	BPA
LMT85LP	Active	Production	TO-92 (LP) 3	1800 LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LP.A	Active	Production	TO-92 (LP) 3	1800 LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LP.B	Active	Production	TO-92 (LP) 3	1800 LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPG	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPG.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPG.B	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPGM	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPGM.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPGM.B	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPM	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPM.A	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85
LMT85LPM.B	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	SN	N/A for Pkg Type	-50 to 150	LMT85

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

PACKAGE OPTION ADDENDUM

www.ti.com 10-Nov-2025

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LMT85:

Automotive : LMT85-Q1

NOTE: Qualified Version Definitions:

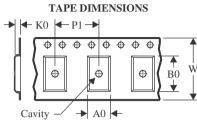
Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Sep-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMT85DCKR	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3

www.ti.com 5-Sep-2025

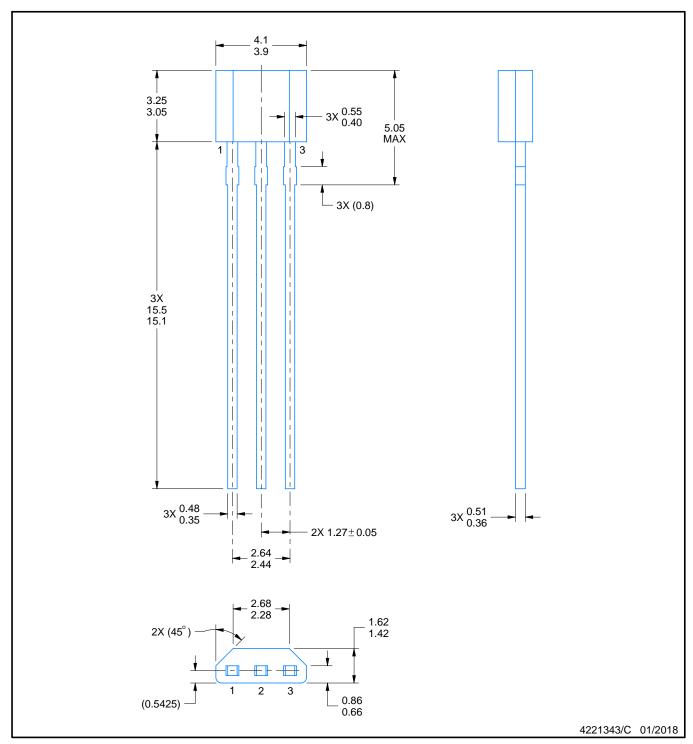


*All dimensions are nominal

Ì	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ı	LMT85DCKR	SC70	DCK	5	3000	208.0	191.0	35.0



TRANSISTOR OUTLINE



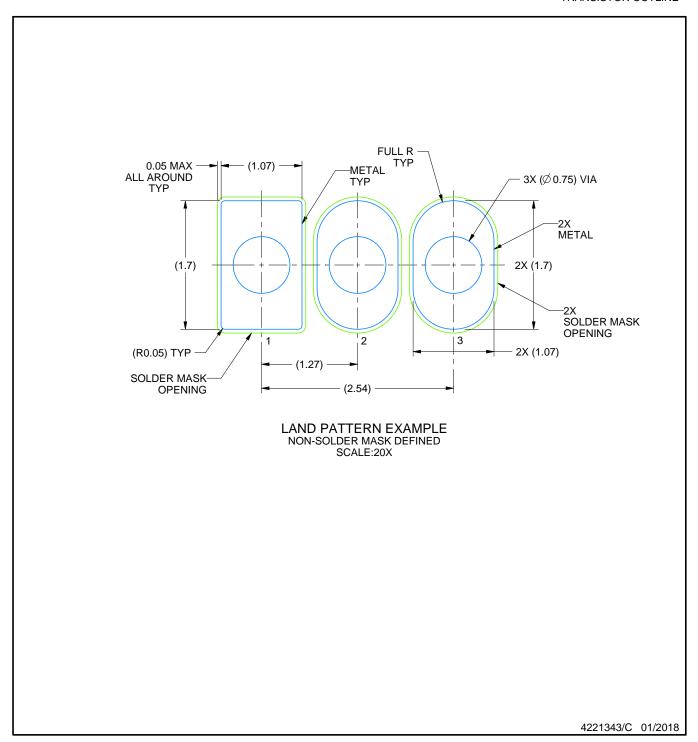
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

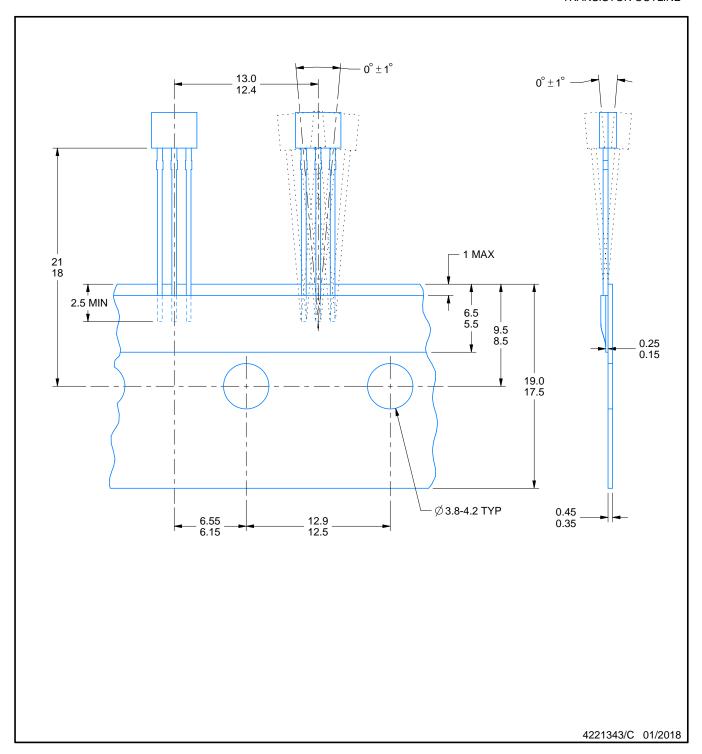
 2. This drawing is subject to change without notice.



TRANSISTOR OUTLINE

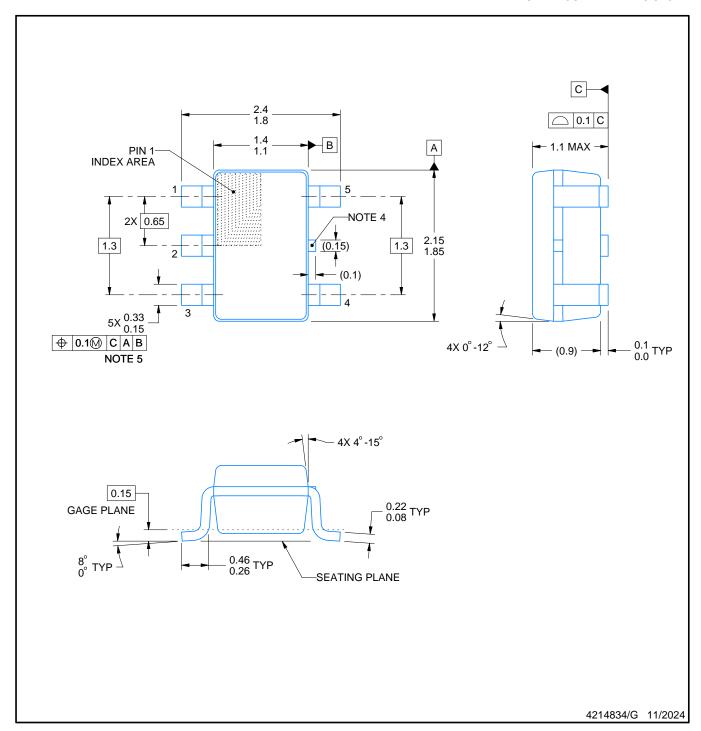


TRANSISTOR OUTLINE





SMALL OUTLINE TRANSISTOR



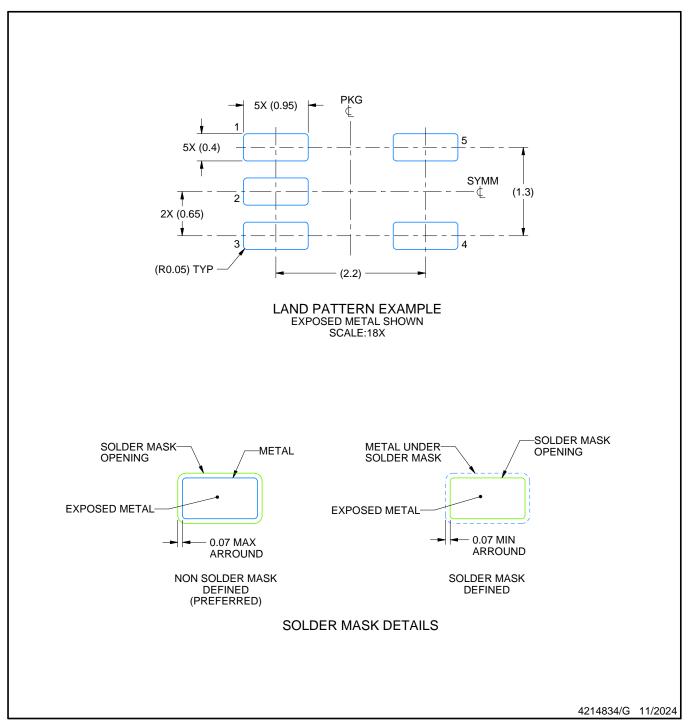
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



SMALL OUTLINE TRANSISTOR

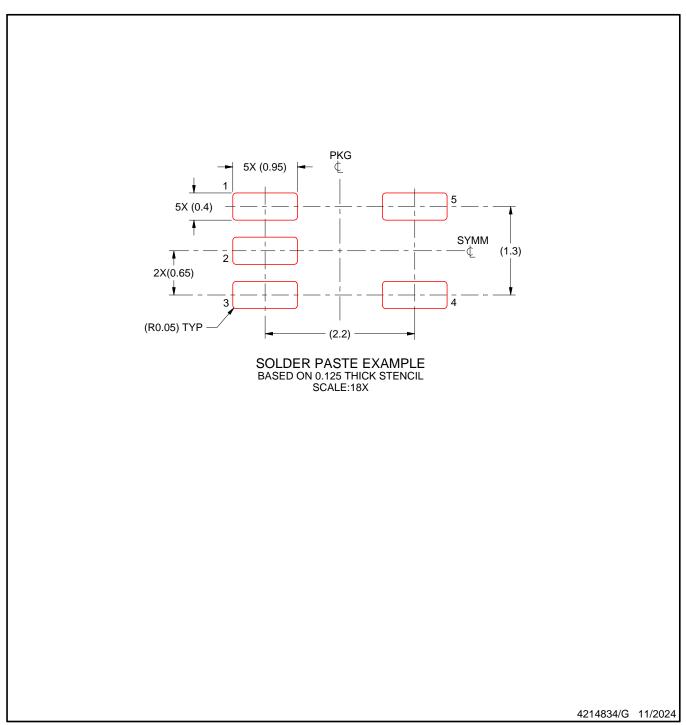


NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



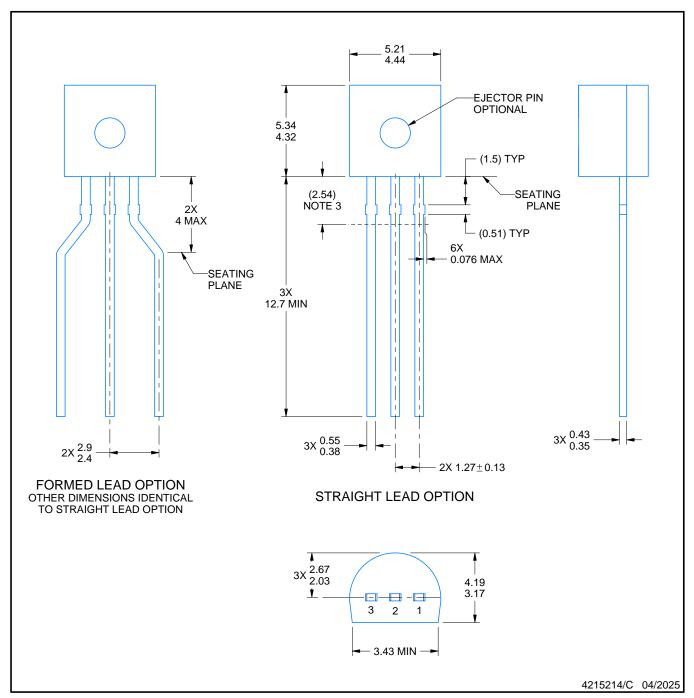
NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.



TO-92 - 5.34 mm max height

TO-92



NOTES:

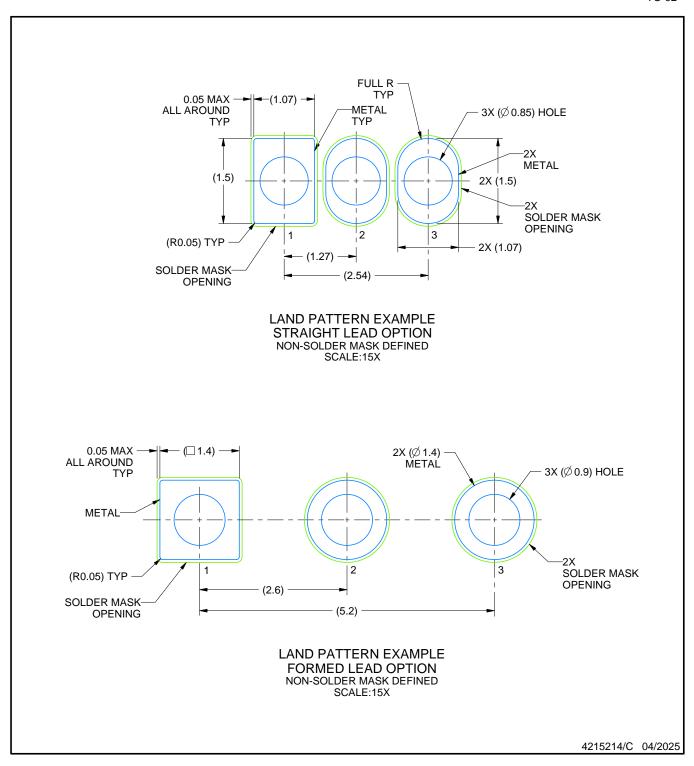
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. Lead dimensions are not controlled within this area. 4. Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

 - a. Straight lead option available in bulk pack only.
 b. Formed lead option available in tape and reel or ammo pack.
 - c. Specific products can be offered in limited combinations of shipping medium and lead options.
 - d. Consult product folder for more information on available options.

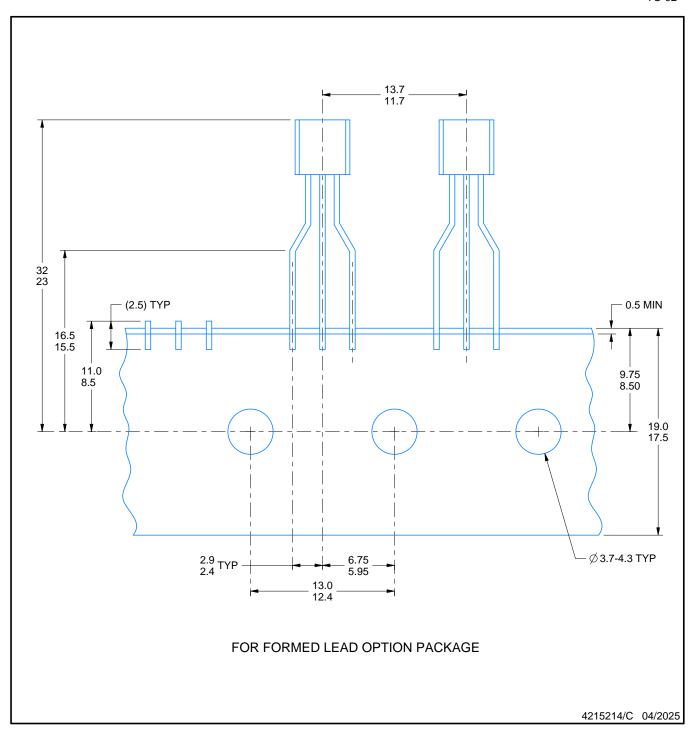


TO-92





TO-92





IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025